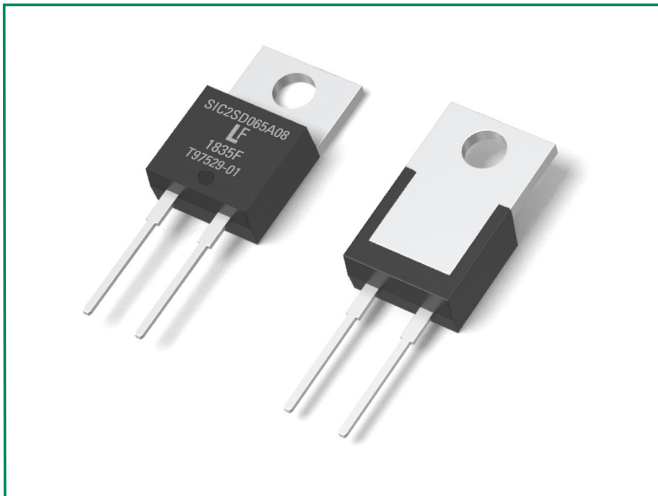


LSIC2SD065A08A 650 V, 8 A SiC Schottky Barrier Diode



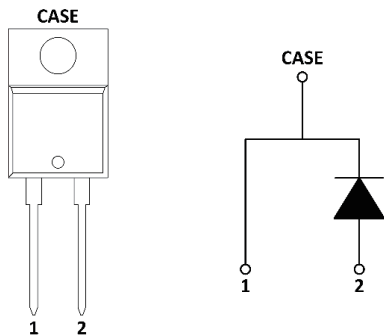
Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-220-2L



Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "Pb-free" logo = Pb-free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	-	650	V
DC Blocking Voltage	V_R	$T_J = 25\text{ °C}$	650	V
Continuous Forward Current	I_F	$T_C = 25\text{ °C}$	23	A
		$T_C = 135\text{ °C}$	10.7	
		$T_C = 150\text{ °C}$	8	
Non-Repetitive Forward Surge Current	I_{FSM}	$T_C = 25\text{ °C}, T_P = 10\text{ ms}, \text{Half sine pulse}$	40	A
Power Dissipation	P_{Tot}	$T_C = 25\text{ °C}$	88	W
		$T_C = 110\text{ °C}$	38	
Operating Junction Temperature	T_J	-	-55 to 175	°C
Storage Temperature	T_{STG}	-	-55 to 150	°C
Soldering Temperature	T_{SOLD}	-	260	°C

Electrical Characteristics (T_J =25 °C unless otherwise specified)

Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	V _F	I _F = 8 A, T _J = 25 °C	-	1.5	1.8	V
		I _F = 8 A, T _J = 175 °C	-	1.85	-	
Reverse Current	I _R	V _R = 650 V, T _J = 25 °C	-	<1	50	μA
		V _R = 650 V, T _J = 175 °C	-	15	-	
Total Capacitance	C	V _R = 1 V, f = 1 MHz	-	415	-	pF
		V _R = 200 V, f = 1 MHz	-	56	-	
		V _R = 400 V, f = 1 MHz	-	41	-	
Total Capacitive Charge	Q _C	V _R = 400 V, $Q_C = \int_0^{V_R} C(V)dV$	-	29	-	nC

Thermal Characteristics

Characteristics	Symbol	Value	Unit
Thermal Resistance	R _{θJC}	1.7	°C/W

Figure 1: Typical Forward Characteristics

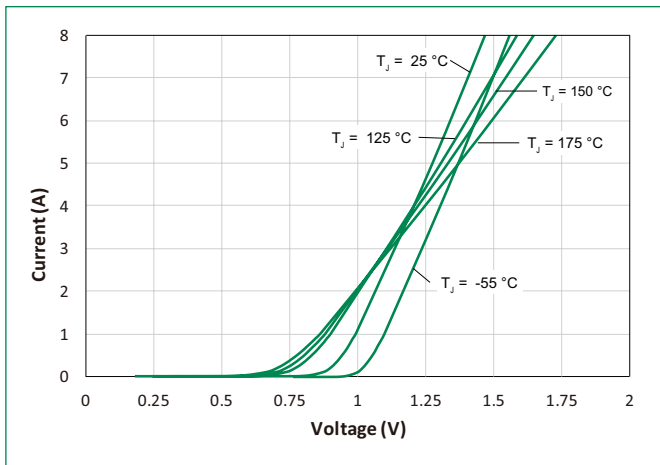


Figure 2: Typical Reverse Characteristics

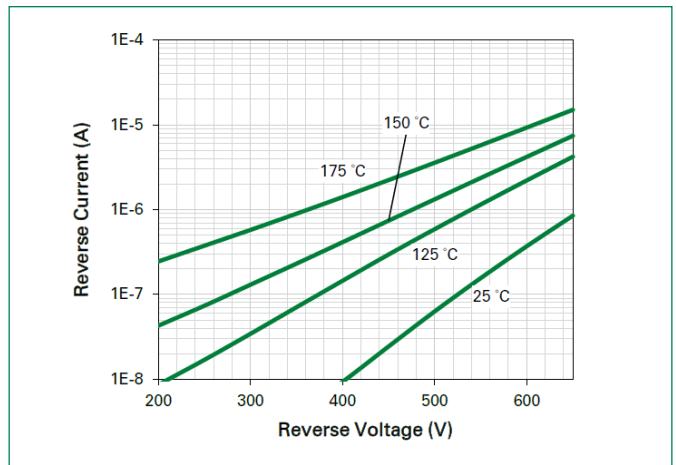


Figure 3: Power Derating

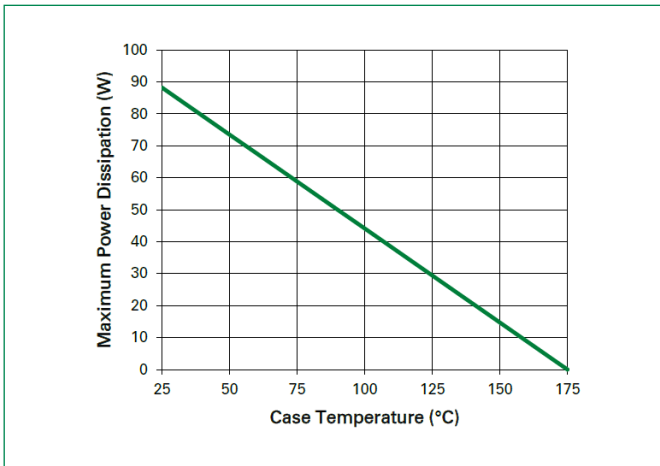


Figure 4: Current Derating

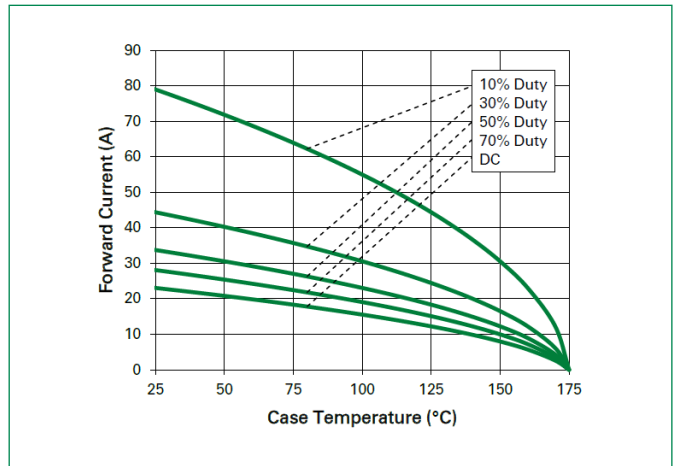


Figure 5: Capacitance vs. Reverse Voltage

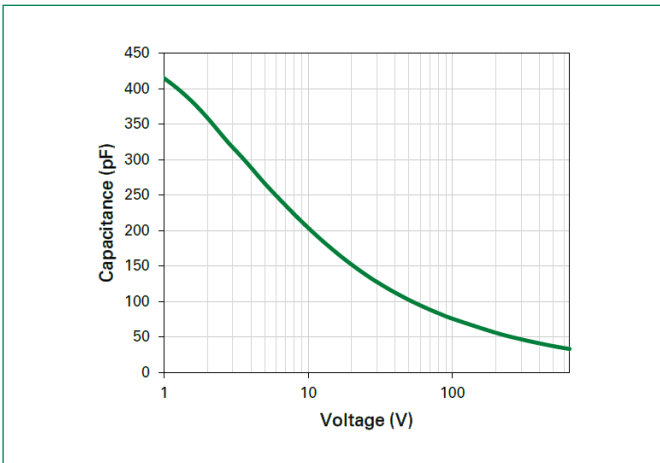


Figure 6: Capacitive Charge vs. Reverse Voltage

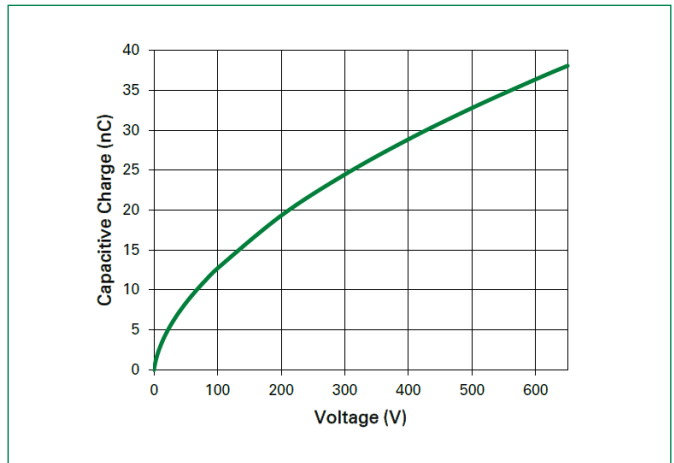


Figure 7: Stored Energy vs. Reverse Voltage

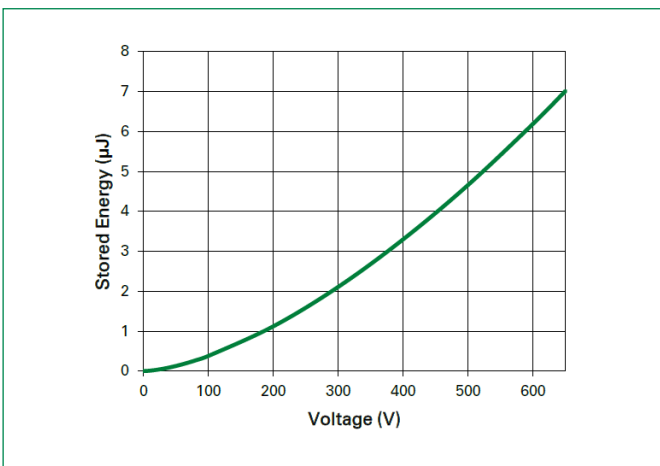
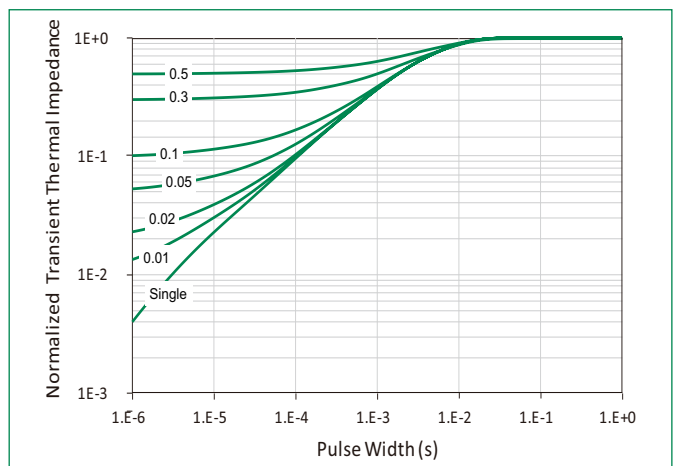
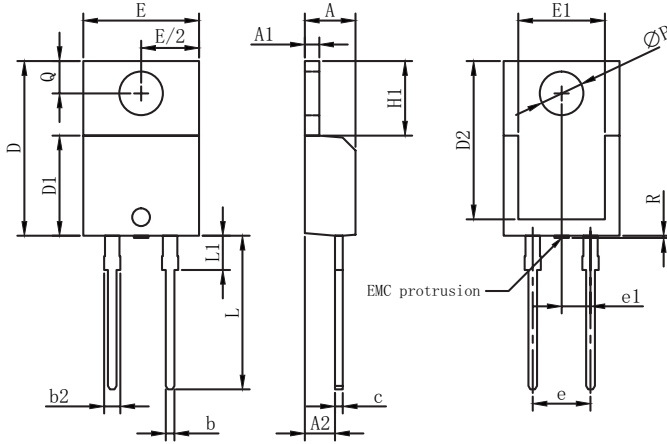


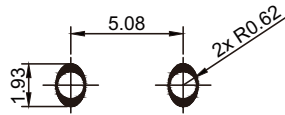
Figure 8: Transient Thermal Impedance



Dimensions-Package TO-220-2L



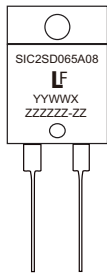
Recommended Solder Pad Layout



UNIT: mm

Symbol	Millimeters		
	Min	Nom	Max
A	4.32	4.45	4.70
A1	1.14	1.27	1.40
A2	2.20	-	2.74
b	0.69	-	0.90
b2	1.17	-	1.62
c	0.36	-	0.60
D	14.90	-	15.90
D1	8.62	-	9.40
D2	12.50	-	12.95
E	9.70	10.18	10.36
E1	7.57	7.61	8.30
e1	-	2.54	-
e	5.03	5.08	5.13
H1	6.30	6.55	6.80
L	12.88	13.50	14.00
L1	2.39	-	3.25
øP	3.50	3.84	3.96
Q	2.65	-	3.05
R	-	-	0.25

Part Numbering and Marking System

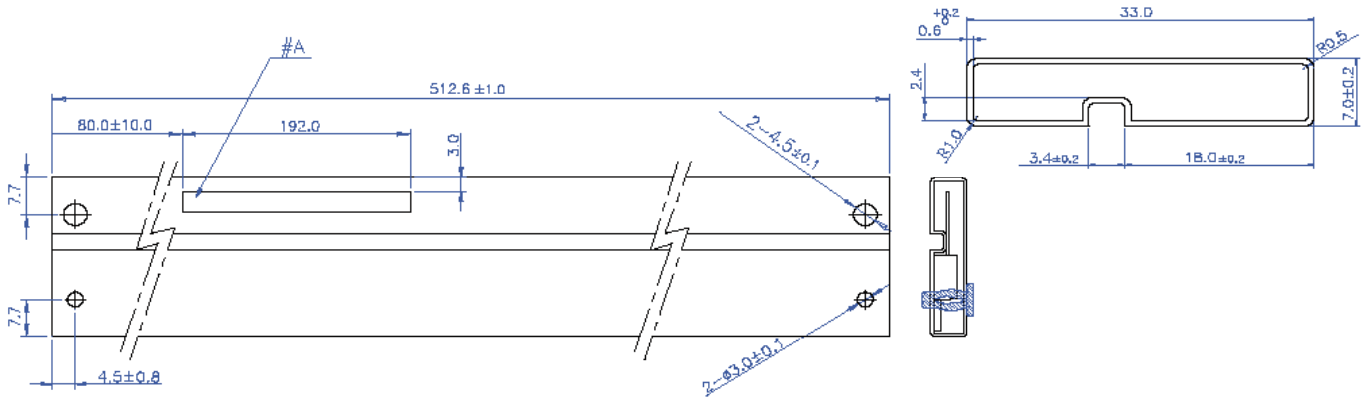


- SIC = SiC Diode
- 2 = Gen2
- SD = Schottky Diode
- 065 = Voltage Rating (650 V)
- A = TO-220 Package (2 Lead)
- 08 = Current Rating (8 A)
- YY = Year
- WW = Week
- X = Special Code
- ZZZZZZ-ZZ = Lot Number

Packing Options

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD065A08A	SIC2SD065A08	Tube(50pcs)	1000

Packing Specification (Tube for TO-220-2L)



[NOTE]

1. TUBE
 - MATERIAL : PVC / PET (WITH ANTISTATIC COATING)
 - COLOR : TRANSPARENCY, RED, YELLOW
 - MARKING #A : BLACK COLOR, LETTER STYLE : Arial
 - Tube Surface Resistance : $10^6 \sim 10^{11} \Omega$ /square
 - ESD (Electro Static Discharge) : less than 100 [volts], 6 Months
 - CAMBAR : 1.5 MAX
2. PIN
 - COLOR : GREEN (ONE PIN MUST BE INSERTED IN LEFT-SIDE OF "ANTISTATIC-" AND ANOTHER PIN IS FREE.)

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